## NSN 5961-01-007-6823

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View Online at https://aerobasegroup.com/nsn/5961-01-007-6823

## Inclosure Material:

Metal

## **Overall Length:**

Between 1.188 inches and 1.252 inches

## Terminal Length:

0.360 inches

### **Overall Height:**

Between 0.250 inches and 0.340 inches

### **Overall Width:**

0.700 inches

## Mounting Facility Quantity:

2

## Internal Configuration:

### Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

## To-66

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

2.00 amperes source cutoff current and 500.00 milliamperes source cutoff current

## Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Precious Material And Location:**

Terminal surface option gold

### **Precious Material:**

Gold

### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

